



2SA 816 · 2SC1626

PNP · NPN SILICON PLANAR EPITAXIAL POWER TRANSISTORS

MICRO ELECTRONICS

CASE TO-220B

THE 2SA816 (PNP) AND 2SC1626 (NPN) ARE SILICON PLANAR EPITAXIAL COMPLEMENTARY PAIR SPECIALLY DESIGNED FOR THE DRIVER STAGES OF 30-50W HI-FI AMPLIFIERS. THEY ARE ALSO SUITABLE FOR MEDIUM SPEED SWITCHING UP TO 2A PEAK CURRENT.



ABSOLUTE MAXIMUM RATINGS

For p-n-p devices, voltage and current values are negative.

Collector-Base Voltage	V_{CB0}	80V
Collector-Emitter Voltage	V_{CEO}	80V
Emitter-Base Voltage	V_{EB0}	5V
Collector Current	I_C	750mA
Collector Peak Current ($t \leq 10\text{ms}$)	I_{CM}	2A
Total Power Dissipation @ $T_C \leq 25^\circ\text{C}$	P_{tot}	10W
@ $T_A \leq 25^\circ\text{C}$		1.5W
Junction Temperature	T_j	150°C
Storage Temperature Range	T_{stg}	-55 to +150°C

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	TEST CONDITIONS
Collector-Base Breakdown Voltage	BV_{CB0}	80			V	$I_C=0.1\text{mA}$ $I_B=0$
Collector-Emitter Breakdown Voltage	BV_{CEO}^*	80			V	$I_C=10\text{mA}$ $I_B=0$
Collector Cutoff Current	I_{CBO}			0.5	μA	$V_{CB}=30\text{V}$ $I_E=0$
Emitter Cutoff Current	I_{EBO}			1	μA	$V_{EB}=5\text{V}$ $I_C=0$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}^*$			0.5	V	$I_C=500\text{mA}$ $I_B=50\text{mA}$
Base-Emitter Voltage	V_{BE}^*			1	V	$I_C=500\text{mA}$ $V_{CE}=2\text{V}$
D.C. Current Gain (Note)	H_{FE1}^*	70		240		$I_C=150\text{mA}$ $V_{CE}=2\text{V}$
	H_{FE2}^*	40				$I_C=500\text{mA}$ $V_{CE}=2\text{V}$
Current Gain-Bandwidth Product	f_T	50	100		MHz	$I_C=150\text{mA}$ $V_{CE}=2\text{V}$
Collector-Base Capacitance	C_{ob}	2SA816		20	pF	$V_{CB}=10\text{V}$ $I_E=0$
		2SC1626		13	pF	$f=1\text{MHz}$

*Pulse Test : Pulse Width=0.3ms, Duty Cycle=1%

note : H_{FE1} is classified as follows. Group 0 : 70-140, Group Y : 120-240

MICRO ELECTRONICS LTD.

38 HUNG TO ROAD, KWUN TONG, HONG KONG. TELEX 43510
KWUN TONG P. O. BOX69477 CABLE ADDRESS "MICROTRON"
TELEPHONE:- 3-430181-6 3-893969 3-892423

FAX: 3-410321

1-2-BMP

TYPICAL CHARACTERISTICS

($T_A=25^\circ\text{C}$ unless otherwise noted)

